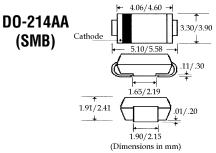
2.0 Amp SURFACE MOUNT PLASTIC SILICON DIODES

Description

Mechanical Dimensions





Features

SMB21...210 Series

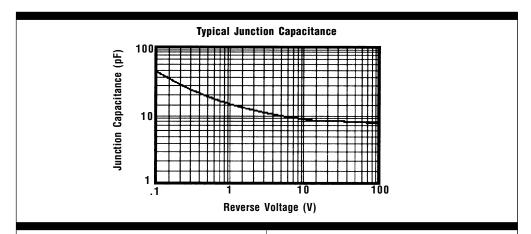
- **LOW COST**
- HIGH CURRENT CAPABILITY
- **HIGH SURGE CAPABILITY**

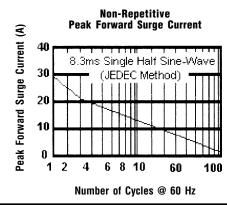
- LOW FORWARD VOLTAGE WITH LOW LEAKAGE CURRENT
- MEETS UL SPECIFICATION 94V-0

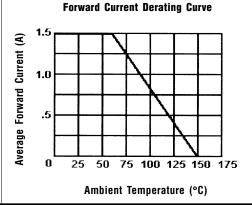
	SMB21 210 Series						Units
Maximum Ratings	SMB21	SMB22	SMB24	SMB26	SMB28	SMB210	
Peak Repetitive Reverse VoltageV _{RRM}	100	200	400	600	800	1000	Volts
RMS Reverse VoltageV _{R(rms)}	70	140	280	420	560	700	Volts
DC Blocking Voltage $V_{\rm DC}$	100	200	400	600	800	1000	Volts
Average Forward Rectified CurrentI _{F(av)}				2.0			Amps
Non-Repetitive Peak Forward Surge CurrentI _{FSM}				50			Amps
Operating & Storage Temperature Range T_J , T_{STRG}			65	to 175			°C
Electrical Characteristics							
Maximum Forward Voltage @ 2.0AV _F				1.1			Volts
Maximum Full Load Reverse CurrentI _R (av)				30			μAmps
				5.0 50			μAmps μAmps
Typical Junction CapacitanceC _J (Note 1)				30			pF



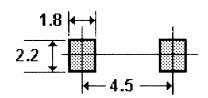
2.0 Amp SURFACE MOUNT PLASTIC SILICON DIODES

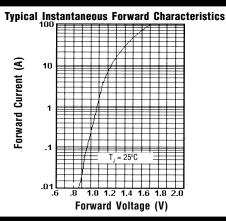






Recommended Soldering Pad Layout





Ratings at 25 Deg. C ambient temperature unless otherwise specified.

Single Phase Half Wave, 60 Hz Resistive or Inductive Load.

For Capacitive Load, Derate Current by 20%.

NOTES: 1. Measured @ 1 MHz and applied reverse voltage of 4.0V.